

Five to Ten Series Cell Lithium-Ion or Lithium-Polymer Battery Protector and Analog Front End

¹FEATURES

- **5, 6, 7, 8, 9, or 10 Series-Cell Primary**
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- **Supply Voltage Range from 7 V to 50 V**
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- - **Pack Protection Control and Recovery** the internal EEPROM.
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	- **Analog Interface for Host Cell Measurement** The analog front end (AFE) outputs allow a host
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APPLICATIONS

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DESCRIPTION

Protection The bq77PL900 is a five to ten series cell lithium-ion • **PMOS FET Drive for Charge and Discharge** battery pack protector. The integrated I²C **FETs FETS EXECUTE: EXECUTE: COMMUNICATIONS** interface allows the bq77PL900 also to be as an analog front end (AFE) for a Host **Capable of Operation with 1-mΩ Sense**
 Capable of Operation with 1-mΩ Sense

controller. Two LDOs, one 5-V, 25-mA and one 3.3-V,

25-mA, are also included and may be used to power

a host controller or support circuit

Low Supply Current of 450 µA Typical The bq77PL900 integrates a voltage translation
Integrated 5-V, 25-mA LDO and the system to extract battery parameters such as system to extract battery parameters such as Integrated 3.3-V, 25-mA LDO **individual cell voltages and charge/discharge current.** Variables such as voltage protection thresholds and **Stand-Alone Mode**
detection delay times can be programmed by using

– Individual Cell Monitoring The bq77PL900 can act as a stand-alone self-contained battery protection system (stand-alone mode). It can alternatively be combined with a host **– Programmable Threshold and Delay Time for**
 a microcontroller to offer fuel gauge or other battery
 - Overvoltage (host-control mode).

(host-control mode).

– Undervoltage The bq77PL900 provides full safety protection for overvoltage, undervoltage, overcurrent in discharge, **– Short Circuit in Discharge** and short circuit in discharge conditions. When the EEPROM programmable safety thresholds are **– Fixed Overtemperature Protection** reached, the bq77PL900 turns off the FET drive **Host Control Mode**
 Algebra 2 autonomously. No external components are needed
 Algebra 2 and to configure the protection features **– I²C Interface to Host Controller** to configure the protection features.

controller to observe individual cell voltages and **– Host-Controlled Protection Recovery** charge/discharge currents. The host controller's analog-to-digital converter connects to the **– Host-Controlled Cell Balancing** bq77PL900 to acquire these values.

Cell balancing can be performed autonomously, or the host controller can activate it individually via a cell • **Cordless Power Tools** bypass path integrated into the bq77PL900. Internal • **Power Assisted Bicycle/Scooter** control registers accessible via the I²C interface **Uninterruptible Power Supply (UPS) Systems** configure this operation. The maximum balancing
Medical Equipment configure the bypass current is set via an external series resistor bypass current is set via an external series resistor • **Portable Test Equipment** and the internal FET-on resistance (typically 400 Ω). Optionally, external bypass cell balance FETs can be used for increased current capability.

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

[bq77PL900](http://focus.ti.com/docs/prod/folders/print/bq77pl900.html)

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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

TYPICAL IMPLEMENTATION

Figure 1. Stand-Alone Mode

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Product Folder Link(s): *[bq77PL900](http://focus.ti.com/docs/prod/folders/print/bq77pl900.html)*

Sense Resistor

Overload Protection

Short-Circuit Protection

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Pack –

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Battery Capacity Monitor

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PIN DETAILS

Pin Out Diagram

TERMINAL FUNCTIONS

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TERMINAL FUNCTIONS (continued)

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FUNCTIONAL BLOCK DIAGRAM

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B0325-01

PACK–

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PACK+

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4 SAFETY STATE OVERVIEW

Figure 3. Stand-Alone Mode

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Table 1. Stand-Alone STATUS Bit, XALERT and FET Transition Summary

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Figure 4. Host-Control Mode

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ORDERING INFORMATION

(1) The bq77PL900 can be ordered in tape and reel by adding the suffix R to the orderable part number, I.e., bq77PL900DLR.

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ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)⁽¹⁾ (2)

(1) Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under *Recommended Operating Conditions* is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltages are with respect to ground of this device except VCn - VC(n+1), where n=1 to 10 cell voltage.

DISSIPATION RATINGS

RECOMMENDED OPERATING CONDITIONS

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ELECTRICAL CHARACTERISTICS

BAT = PACK = 7 V to 50 V, T_A = -25°C to 85°C, typical values stated where T_A = 25°C and BAT = PACK = 36 V (unless otherwise noted)

(1) Charge pump starts working when (I_{REG33} + I_{REG5}) > 3 mA.
(2) Not 100% tested, assured by design up to 125°C

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ELECTRICAL CHARACTERISTICS (continued)

BAT = PACK = 7 V to 50 V, T_A = -25°C to 85°C, typical values stated where T_A = 25°C and BAT = PACK = 36 V (unless otherwise noted)

(4) STATE_CONTROL [VGAIN] = 1, FUNCTION_CONTROL [VAEN] = 1, CELL_SEL[CAL2] = 0, [CAL0] = 1, [CAL0] = 1

(5) STATE_CONTROL [VGAIN] = X, FUNCTION_CONTROL [PACK] = 1, [VAEN] = 1

(6) STATE_CONTROL [VGAIN] = X, FUNCTION_CONTROL [BAT] = 1, [VAEN] = 1

(7) STATE_CONTROL [VGAIN] = 0, FUNCTION_CONTROL [VAEN] = 1, CELL_SEL[CAL2] = 0, [CAL0] = 0, [CAL0

(8) STATE_CONTROL [VGAIN] = 1, FUNCTION_CONTROL [VAEN] = 1, CELL_SEL[CAL2] = 0, [CAL0] = 0, [CAL0] = 0

(9) STATE_CONTROL [IGAIN] = X, FUNCTION_CONTROL [IAEN] = 1, [IACAL] = 1

(10) STATE_CONTROL [IGAIN] = 0, FUNCTION_CONTROL [IAEN] = 1, [IACAL] = 0

 (11) STATE_CONTROL $[IGAIN] = 1$, FUNCTION_CONTROL $[IAEN] = 1$, $[IACAL] = 0$

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ELECTRICAL CHARACTERISTICS (continued)

BAT = PACK = 7 V to 50 V, T_A = -25°C to 85°C, typical values stated where T_A = 25°C and BAT = PACK = 36 V (unless otherwise noted)

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ELECTRICAL CHARACTERISTICS (continued)

BAT = PACK = 7 V to 50 V, T_A = -25°C to 85°C, typical values stated where T_A = 25°C and BAT = PACK = 36 V (unless otherwise noted)

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I ²C COMPATIBLE INTERFACE

BAT = PACK = 7 V to 50 V, $T_A = -25^{\circ}$ C to 85°C, typical values stated where $T_A = 25^{\circ}$ C and BAT = PACK = 36 V (unless otherwise noted)

Figure 5. I²C-Like I/F Timing Chart

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GENERAL OPERATIONAL OVERVIEW

Stand-Alone Mode and Host Control Mode

The bq77PL900 has two operational modes, stand-alone mode and host-control mode. The mode is switched by *STATE_CONTROL [HOST]*. In stand-alone mode, the battery protection is managed by the bq77PL900 without the need for any external control. In this mode, the CHG and DSG FETs are driven ON and OFF automatically and cell balancing is processed by a fixed algorithm if enabled by *OCDELAY[CBEN]*). In this mode, ¹²C communication is enabled, and a host can read the registers and set *STATE_CONTROL [HOST]* but cannot control any output or function such as Vcell AMP enable.

In host control mode, a host microcontroller can obtain battery information such as voltage and current from the bq77PL900 analog interface. This allows the host, such as a microcontroller, to calculate remaining capacity or implement an alternative cell balancing algorithm. In this mode, the bq77PL900 still detects cell protection faults and acts appropriately, although the recovery method is different from that in stand-alone mode. The host controller has control over the recovery method and FET action after the protection state has been entered. Table 3 contains further details of the protection action differences.

Table 3. Stand-Alone Mode and Host Control Mode Protection Summary

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Normal Operation Mode

When all cell voltages are within the range of V_{UV} to V_{OV}, and the CHG and DSG FETs are turned ON, the cells are charged and discharged at any time.

Figure 6. Normal Operation Mode

Battery Protection

The bq77PL900 fully integrates battery protection circuits including cell overvoltage, undervoltage, and overcurrent in discharge and short circuit in discharge detection. Each detection voltage can be adjusted by programming the integrated EEPROM. Also, the detection delay time can be programmed as shown in Table 4.

CAUTION:

Only a maximum of three programming cycles should performed to ensure data stability.

Table 4. Detection Voltage, Detection Delay Time Summary

Cell Overvoltage and Cell Undervoltage Detection

The cell overvoltage and cell undervoltage detection circuit consists of a sample-and-hold (S/H) circuit and two comparators.

The S/H period is about 120 µs for each cell, and S/H is performed sequentially on each cell. Once all of the cells are checked, the bq77PL900 waits about 50 mS for the next S/H.

[bq77PL900](http://focus.ti.com/docs/prod/folders/print/bq77pl900.html)

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Figure 7. Cell Voltage Monitoring Circuit

Cell Overvoltage Detection and Recovery

Cell overvoltage detection is the same as host control mode for the FET OFF state, but the recovery conditions are different. The CHG FET is turned OFF if any one of the cell voltages remains higher than V_{OV} for a period greater than $t_{\rm OV}$. As a result, the cells are protected from an overcharge condition. Also XLAERT changes from High to Low. Both V_{OV} and t_{OV} can be programmed in the internal EEPROM.

Recovery in Host Control Mode

The recovery condition is as follows:

- 1. All cell voltages become lower than V_{OV} (ΔV_{OVH} is ignored).
- 2. Additionally, the host must send a sequence of firmware commands to the bq77PL900 to turn ON the CHG FET.

The command sequence required is as follows:

- 1. The host must toggle LTCLR from 0 to 1 and then back to 0.
- 2. Then set the CHG control bit to 1. To reset XLAERT high, the host must read the status register.

[Figure 8](#page-20-0) illustrates the circuit schematic in overvoltage protection mode in Host Control Mode. [Figure 9](#page-21-0) illustrates the timing of this protection mode.

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Figure 8. Overvoltage in Host-Control Mode

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Figure 9. OV and OV Recovery Timing in Host-Control Mode

Recovery in Stand-Alone Mode

The recovery condition occurs when all cell voltages become lower than $(V_{\text{OV}} - \Delta V_{\text{OVH}})$.

Figure 10 illustrates the circuit schematic in overvoltage protection mode in stand-alone mode. [Figure 11](#page-23-0) illustrates the timing of this protection mode.

Figure 10. Cell Overvoltage Protection Mode in Stand-Alone Mode

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Figure 11. OV and OV Recovery Timing in Stand-Alone Mode

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7.14.1 Cell Undervoltage Detection and Recovery

When any one of the cell voltages falls below V_{UV} for a period of t_{UV} , the bq77PL900 enters the undervoltage mode. At this time, the DSG FET is turned OFF and XALERT driven low. Both V_{UV} and t_{UV} can be programmed in the internal EEPROM.

Figure 12. Cell Undervoltage Protection Mode in Host Mode and Stand-Alone Mode (Attaching a Charger)

In Host-Control Mode

Cell undervoltage protection recovery conditions are when:

- 1. All cell voltages become higher than $(V_{UV} + \Delta V_{UVH})$, or
- 2. All cell voltages are higher than V_{UV} AND a charger is connected between PACK+ and PACK–, noting that PACK+ voltage must be higher than BAT due to the diode forward voltage.

The bq77PL900 monitors the voltage difference between the PACK+ and BAT pins. When a difference higher than 0.4V (typ.) is seen, it is interpreted that a charger has been connected.

Figure 12 illustrates the circuit schematic in undervoltage protection mode.

In some applications, it is required not to turn OFF the DSG FET suddenly. In these cases, by setting *UVLEVLE [UVFET_DIS]* **= 1**, only XALERT is driven low in response to entering an undervoltage condition. The host can turn OFF the DSG FET to protect the undervoltage condition. When the bq77PL900 recovery condition is satisfied, the host must send a sequence of firmware commands to the bq77PL900. The firmware command sequence to turn ON the DSG FET is as follows:

- 1. The host must toggle LTCLR from 0 to 1 and back to 0.
- 2. Then the host must set the DSG ON bit to 1.
- 3. Then the host can read the status register to reset XALERT high.

[Figure 13](#page-25-0) and [Figure 14](#page-25-0) illustrate the timing chart of protection mode.

[bq77PL900](http://focus.ti.com/docs/prod/folders/print/bq77pl900.html)

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Figure 14. UV and UV Recovery Timing Host Control Mode (UVFET_DIS = 1)

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In Stand-Alone Mode

On detecting entry to undervoltage mode, the bq77PL900 moves to the *shutdown* power mode.

When a charger is attached, the bq77PL900 wakes up from shutdown mode. If cell voltages are lower than the undervoltage condition, the DSG FET is turned OFF and XALERT driven low. During periods when a charger is attached, the bq77PL900 never changes to shutdown mode.

When the undervoltage recovery condition is satisfied, the DSG FET turns ON and XLAERT is reset high.

Figure 15. UV and UV Recovery in Stand-Alone Mode

Overcurrent in Discharge (OCD) Detection

The overcurrent in discharge detection feature detects abnormal currents in the discharge direction via measuring the voltage across the sense resistor (V_{OCD}) and is used to protect the pass FETs, cells, and any other inline components from abnormal discharge current conditions. The detection circuit also incorporates a blanking delay period ($t_{\rm OCD}$) before turning OFF the pass FETs. Both $V_{\rm OCD}$ and $t_{\rm OCD}$ can be programmed in internal EEPROM.

Short Circuit in Discharge (SCD) Detection

The short circuit in discharge detection feature detects severe discharge current via measuring the voltage across the sense resistor (V_{SCD}) and is used to protect the pass FETs, cells, and any other inline components from severe current conditions. The detection circuit also incorporates a blanking delay period (t_{SCD}) before turning OFF the pass FETs. Both V_{SCD} and t_{scD} can be programmed in the internal EEPROM.

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7.14.1 Overcurrent in Discharge and Short Circuit in Discharge Recovery

In host-control mode, the host must send a sequence of firmware commands to the bq77PL900 to recover from overcurrent and short-circuit currents. The command sequence to turn ON the DSG and CHG FETs is as follows:

- 1. The host must toggle LTCLR from 0 to 1 and back to 0.
- 2. Then set the DSG and CHG control bits to 1. To reset XALERT high, the STATUS register must be read.

In stand-alone mode, the bq77PL900 has two methods to recover from overcurrent and short-circuit conditions by setting the SOR bit of OCD_CFG.

SOR = 0: Recover comparator is active after 12.8 s. An internal comparator monitors the PACK+ voltage and when the PACK+ voltage reaches V_{RECSC} , the overcurrent in discharge recovers. When the bq77PL900 detects a charger is attached, the DSG and CHG FETs turn ON and XALERT is reset High.

SOR = 1: After 12.8 s, the bq77PL900 automatically recovers from OC and SC. The DSG and CHG FETs turn ON and XALERT is reset high. If the OC or SC condition is still present, OC and SC is detected again and the recovery/detection cycle continues until the fault is removed.

Figure 16. Overcurrent and Short-Circuit Protection Modes

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Table 5. Detection and Recovery Condition Summary (Stand-Alone Mode)

Table 6. Detection and Recovery Condition Summary (Host-Control Mode)

(1) Host is required to set and clear LTCLR, then turn on the FETs.

Low-Dropout Regulators (REG1 and REG2)

The bq77PL900 has two low dropout (LDO) regulators that provide power to both internal and external circuitry. The inputs for these regulators can be derived from the PACK or BAT terminals (see the Initialization section for further details). The output of REG1 is typically 5 V, with a minimum output capacitance of 2.2 μ F required for stable operation. It is also internally current-limited. During normal operation, the regulator limits the output current, typically to 25 mA. The output of REG2 is typically 3.3 V, also with a minimum output capacitance of 2.2 µF for stable operation, and it is also internally current-limited.

Until the internal regulator circuit is correctly powered, the DSG and CHG FETs are driven OFF.

Initialization

From a shutdown situation, the bq77PL900 requires a voltage greater that the start-up voltage ($V_{STARTUP}$) applied to the PACK pin to enable its integrated regulator and provide the regulator power source. Once the REG1 and REG2 outputs become stable, the power source of the regulator is switched to BAT.

After the regulators have started, they then continue to operate through the BAT input. If the BAT input is below the minimum operating range, then the bq77PL900 does not operate until the supply to the PACK input is applied.

If the voltage at REG2 falls, the internal circuit turns off the CHG and DSG FETs and disables all controllable functions, including the REG1, REG2, and TOUT outputs.

Series Configuration of Five to Ten Cells

Unused cell inputs are required to be shorted to the uppermost-voltage-connected terminal. For example, in a five-cell configuration, VC1 to VC5 are shorted to VC6. In a 9-cell configuration, VC1 is shorted to VC2.

The CNF0, CNF1, and CNF2 pins should be connected to VLOG = logic 1 (through a10-kΩ resistance) or GND = logic 0 (directly) according to the desired cell configuration as seen in Table 7.

Table 7. Cell Configuration

Delay Time Zero

The ZEDE pin enables EEPROM-programmed detection delay times when connected with GND (normal operation). The detection delay time is set to 0 when this pin is connected with VLOG. This is typically used in battery manufacturing test only.

Cell Voltage Measurement

The cell voltage is translated to allow a host controller to measure individual series elements of the battery. The series element voltage is presented on the VOUT terminal. The cell voltage amplifier gain can be selected as one of the following two equations. The VOUT voltage gain is selected by *STATE_CONTROL [VGAIN]*. VOUT is internally connected to ground when disabled.

 V_{OUT} 1 = 0.975 – {(Cell voltage) \times 0.15} when VGAIN = 0 or

 V_{OUT} 2 = 1.2 – {(Cell voltage) \times 0.20} when VGAIN = 1

The total pack voltage can also be monitored. The PACK voltage output is enabled or disabled by *FUNCTION_CONTROL [PACK]*.

 V_{OUT} 3 = (Total pack voltage) \times 0.02 when PACK = 1

The total pack voltage can also be monitored. The BAT voltage output is enabled or disabled by *FUNCTION_CONTROL [BAT]*.

 V_{OUT} 4 = (Total battery voltage) \times 0.02 when BAT = 1

Cell Voltage Measurement Calibration

The bq77PL900 cell-voltage monitor consists of a sample-and-hold (S/H) circuit and differential amplifier.

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Figure 17. Cell Voltage Monitoring Circuit

To calibrate the VCELL output, it must measure a 2.5-V signal, but 2.5 V is beyond the ADC input range of most analog-to-digital converters used in these applications. The bq77PL900 is designed to measure the 2.5 V through a differential amplifier first, which is where the calibration procedure starts.

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Step 1

Set CAL2 = 0, CAL1 = 0, CAL0 = 1, CELL[4:1] = 0, VAEN = 1

Measure the output voltage of the differential amplifier at 0-V input (both inputs of the differential amplifier are connected to GND). The output voltage includes the offset and is represented by:

 $Vd_{\text{OUT}}(0V)$ = measured output voltage of differential amplifier at 0-V input

(This value includes an offset voltage (V_{OS}) and a reference voltage.)

Step 2

Set CAL2 = 0, CAL1 = 1, CAL0 = 1, VAEN = 1

VREF is trimmed to 0.975 V or 1.2 V within ±2%. Then measure internal reference voltage VREF directly from VOUT:

VREF $m =$ measured reference voltage (0.975 V or 1.2 V)

Step 3

Set CAL2 = 0, CAL1 = 1, CAL0 = 0, CELL $[4:1] = 0$, VAEN = 1

Measure the scaled REF voltage through the differential amplifier.

 $Vd_{\text{OUT}}(VREF\,m)$ = The output voltage, including the scale factor error and offset

= VREF + (1 + K) × VOS – K × VREF

 $=$ VREF_m + (1 + Kd_{ACT}) × V_{OS} – Kd_{ACT} × VREF_m

where: $VREF_{m}+(1+Kd_{ACT})\times V_{OS}=Vd_{OUT}(OV)$

 $Kd_{ACT} = (Vd_{OUT}(OV) - Vd_{OUT}(VREF_m)) / VREF_m$

 $=$ (measured value at step 1 – measured value at step 3)/ measured value at step 2

Calibrated differential voltage is calculated by:

Vdout = VREF + $(1 + K) \times V_{OS} - K \times V$ din $= Vd_{\text{OUT}}(0V) - Kd_{\text{ACT}} \times Vdi$ n

Where: V din $=$ input voltage of differential amp lifier

Step 4

Set CAL2 = 1, CAL1 = 0, CAL0 = 0, CELL[4:1] = 0, VAEN = 1

Measure scaled REF(2.5V) though differential amp,

Some TI-Benchmarq gas gauges cannot measure 2.5 V directly, because the ADC input voltage is 1 V. So to measure the 2.5-V internal reference voltage, use a differential amplifier as a method to scale down the measurement value.

 $Vdot(2.5V)$ = measured differential amp output voltage at the 2.5-V input

Already, differential amplifier calibration was performed in steps 1, 2, and 3.

So VREF_2.5V is presented by

 $VREF_2.5V = \{ Vd_{OUT}(OV) - Vdout(2.5V)\}/Kd_{ACT}$

Step 5

Set CAL2 = 1, CAL1 = 0, CAL0 = 1, CELL2 = 0, CELL1 = 0, VAEN = 1 Vout(0.975V or 1.2V) = Measure scaled REF (0.975-V or 1.2-V) output voltage S/H and differential amplifier.

Step 6

Set CAL2 = 1, CAL1 = 1, CAL0 = 0, CELL[4:1] = 0, VAEN = 1

Vout $(2.5V)$ = Measure scaled REF $(2.5-V)$ output voltage S/H and differential amp.

Scale factor

 $K_{\text{ACT}} = -(V_{\text{OUT}}(2.5V) - V_{\text{OUT}}(0.975V \text{ or } 1.2V)/(VREF 2.5V - VREF$ m)

 $Vout(0V) = V_{OUT}(2.5V) + K_{ACT} \times VREF$ 2.5V OR

Vout(0V) = $V_{\text{OUT}}(0.975V \text{ or } 1.2V) + K_{\text{ACT}} \times VREF_{\text{M}}$

Cell voltage is calculated by as follows:

 $VCh - VC(n + 1) = \{Vout(0V) - V_{OUT}\} / K_{ACT}$

Current Monitor

Discharge and charge currents are translated to allow a host controller to measure accurately current, which measurement can then be used for additional safety features or calculating the remaining capacity of the battery. The sense resistor voltage is converted using the following equation. The typical offset voltage is $V_{\text{CHU OFF}}$ (1.2 V typical), although it can be presented on the IOUT pin for measurement, if required.

The output voltage increases when current is positive (discharging) and decreases when current is negative (charging).

 $V_{\text{CURR}} = 1.2 + (I_{\text{PACK}} \times R_{\text{SENSE}}) \times (IGAIN)$

where

State_Control [IGAIN] = 1 then IGAIN = 50 State Control $[IGAIN] = 0$ then $IGAIN = 10$

The current monitor amplifier can present the offset voltage as shown in Table 8. The IOUT pin is enabled or disabled by *FUNCTION_CONTROL [IACAL, IAEN]* and has a default state of OFF. IOUT is internally connected to ground when disabled.

Table 8. IACAL and IAEN Configuration

Cell Balance Control

The integrated cell balance FETs allow a bypass path to be enabled for any one series element. The purpose of this bypass path is to reduce the current into any one cell during charging to bring the series elements to the same voltage. Series resistors placed between the input pins and the positive series element nodes limits the bypass current value. Series input resistors between 500 Ω and 1 kΩ are recommended for effective cell balancing.

In host-control mode, individual series element selection is made via *CELL_BALANCE [CBAL1, CBAL2, CBAL3, CBAL4, CBAL5, CBAL6, CBAL7, and CBAL8]* and *FUNCTION_CONTROL [CBAL9, CBAL10]*.

In stand-alone mode, cell balancing works as shown in [Figure 19](#page-33-0). When a certain cell (cell A) voltage reaches cell overvoltage, the battery charging stops and then cell balance starts working at ta. The cell-A voltage decreases by the bypass current until the voltage reaches ($V_{\text{OV}} - \Delta V_{\text{OV}}$). Cell-B voltage does not change during the period because cell balancing works only for the cell that reached V_{OV} . At tb, battery charging starts again. Cell A and cell B have been charged in this period until cell-A voltage reaches V_{OV} again. The voltage difference between cell A and cell B becomes smaller when the bq77PL900 repeats the foregoing cycle. The bq77PL900 stops cell balance when cell overvoltage protection has released.

The bq77PL900 is designed to prevent cell balancing on adjacent cells or on every other cell. For example, if cell overvoltage happened to cell 8, cell 7 (cell 7 is next to cell 8) and cell 3 (cell 3 is **not** next to cell 8 or cell 7), then cell balancing starts for cell 8 and cell 3 first. When the cell-8 voltage is back to normal, then cell balancing starts for cell 7.

While the bq77PL900 monitors the overvoltage and undervoltage, cell balancing is automatically turned off. This configuration is supported for both modes (host-control and stand-alone modes).

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 $\text{SLUSS44B–JUNE } 2008-\text{REVISED JANUARY } 2009 \newline \text{MWW-} \text{Licom } 1000 \newline \text{MWW-} \text{Licom } 10$

Figure 19. Cell Balancing Timing Chart (Automatic)

Thermistor Drive Circuit (TOUT), Thermistor Input (TIN)

The TOUT pin is powered by REG2, can be enabled via *FUNCTION_CONTROL [TOUT]* to drive an external thermistor, and is OFF by default. A 10-kΩ, 25°C NTC (e.g., Semitec 103AT) thermistor is typical. The maximum output impedance is 100 $Ω$.

The bq77PL900 monitors the battery temperature as shown in Figure 20. A voltage divided by the NTC thermistor and reference resistor is connected to TIN. The bq77PL900 compares the TIN voltage with the internal reference voltage (0.975V), and when $V_{TIN} < V_{RFF}$ the bq77PL900 turns OFF the CHG and DSG FETs and sets *STATUS [OVTEMP]*.

In host-control mode, the host should enable and disable TOUT.

Figure 20. Temperature Monitoring Circuit

General-Purpose Open-Drain Drive (GPOD)

The GPOD output is enabled or disabled by *OUTPUT_CONTROL [GPOD]* and has a default state of OFF.

In stand-alone mode, this pin is used for driving the 0-V/precharge FET for zero-voltage battery charging by OCD_CFG *[ZVC] = 1*.

Alerting the Host (XALERT)

In both modes, the XALERT pin is available and is driven low when faults are detected. The method to clear the XALERT pin is different in stand-alone mode than in host-control mode. In stand-alone mode, XLAERT is cleared when all of the faults are cleared. In host-control mode, the host must toggle (from 0, set to 1, then reset to 0) *OUTPUT_CONTROL [LTCLR]* and then read the *STATUS* register.

Alerting the Host (LTCLR)

In host-control mode, when a protection fault occurs, the state is latched. The fault flag is unlatched by toggling (from 0, set to 1 then reset to 0) *OUTPUT_CONTROL [LTCLR]*. The OCD, SCD, OV, and UV bits are unlatched by this function. Now the FETs can be controlled by programming the *OUTPUT_CONTROL* register, and the XALERT output can be cleared by reading the *STATUS* register. When detecting overvoltage or undervoltage faults, LTCTR changes are ignored. After a period of 1 ms, it must send an LTCLR command.

Figure 21. LTCLR and XLAERT Clear Timing (Host-Control Mode)

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The XRST open-drain output pin is triggered on activation of the VREG1 or VREG2 output. This holds the host controller in reset for t_{RST}, allowing V_{VREG1} or V_{VREG2} to stabilize before the host controller is released from reset.

The XRST output and monitoring voltage is supplied by the source of VLOG. When VLOG is connected to VREG1, the XRST output level is V_{VREG1} and monitors the activation of VREG1. When VLOG is connected to VREG2, the XRST output level is V_{VREG2} and monitors the activation of VREG2.

When V_{VRFG1} or V_{VRFG2} voltage is below the output specifications, XRST is active-low (0.8 \times VLOG). When V_{BAT} is below 7 V, VREG1 and VREG2 stop, then XRST goes low. If a host has a problem with a sudden reset signal, it is recommended monitoring the battery voltage to avoid it, e.g., burnout detection.

Figure 22. XRST Timing Chart – Power Up and Power Down

 $\text{SLUSS44B–JUNE } 2008-\text{REVISED JANUARY } 2009 \newline \text{MWW-} \text{Licom } 1000 \newline \text{MWW-} \text{Licom } 10$

EEPROM Write Sequence

The bq77PL900 has integrated configuration EEPROM for OV, UV, OCD, and SCD thresholds and delays. The appropriate configuration data is programmed to the configuration registers, and then 0xe2 is sent to the EEPROM register to enable the programming supply voltage. By driving the EEPROM pin (set high and then low), the data is written to the EEPROM.

When supplying BAT, care should be taken not to exceed VCn – VC(n + 1), (n = 1 to 10) > 5 V. If BAT and VC1 are connected onboard, it is recommended that all cell-balance FETs be ON where each input voltage is divided with the internal cell-balance ON resistance.

The recommended voltage at BAT or PACK for EEPROM writing is 20 V. When supplying VBAT, care is needed to ensure VBAT does not exceed the $V Cn - V C(n + 1)$, $(n = 1$ to 10) absolute maximum voltage. If BAT and VC1 are connected onboard, supplying 7.5 V is recommended to activate the bq77PL900 and turn ON all cell-balance FETs.

Then increase the power supply up to 20 V. By this method, each input voltage is divided with the internal cell-balance ON resistance.

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Figure 23. EEPROM Data-Writing Flow Chart

Power Modes

The bq77PL900 has two power modes, normal and shutdown. Table 9 outlines the operational functions during the two power modes.

Table 9. Power Modes

Shutdown Mode

In host-control mode, the bq77PL900 enters shutdown mode when it receives the shutdown command, *STATE_CONTROL [SHDN]* set. First, the DSG FET is turned OFF, and then after the pack voltage goes to 0 V, the bq77PL900 enters shutdown mode, which stops all functions of the bq77PL900.

In stand-alone mode the bq77PL900 enters shutdown when the battery voltage falls and UV is detected. It turns the DSG FET OFF, and after the pack voltage goes to 0 V, the bq77PL900 enters shutdown mode, which stops all functions.

Exit From Shutdown

If a voltage greater than $V_{STARTUP}$ is applied to the PACK pin, then the bq77PL900 exits from shutdown and enters normal mode.

Parity Check

The bq77PL900 uses EEPROM for storage of protection thresholds, delay times, etc. The EEPROM is also used to store internal trimming data. For safety reasons, the bq77PL900 uses a column parity error checking scheme. If the column parity bit is changed from the written value, then *OUT_CONTROL [PFALT]* is set to 1 and XALERT driven low. In stand-alone mode, both DSG and CHG outputs are driven high, turning OFF the DSG and CHG FETs. The GPOD output is also turned off.

In host-control mode, only *OUT_CONTROL [PFALT]* and the XALERT output are changed, allowing the microprocessor host to control bq77PL900 operation.

Communications

The I²C-like communication provides read and write access to the bq77PL900 data area. The data is clocked via separate data (SDATA) and clock (SCLK) pins. The bq77PL900 acts as a slave device and does not generate clock pulses. Communication to the bq77PL900 can be provided from the GPIO pins of a host controller. The slave address for the bq77PL900 is 7 bits and the value is 0010 000.

The bq77PL900 does NOT have the following functions compatible with the $I²C$ specification.

- The bq77PL900 is always regarded as a slave.
- The bq77PL900 does not support the general code of the I²C specification and therefore does not return an ACK, but may return a NACK.
- The bq77PL900 does not support the address auto-increment, which allows continuous reading and writing.
- The bq77PL900 allows data to be written to or read from the same location without resending the location address.

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Figure 26. I²C-Bus Read From bq77PL900: Protocol B

SLUS844B–JUNE 2008–REVISED JANUARY 2009 .. **www.ti.com**

Register Set

The bq77PL900 has 12 addressable registers. These registers provide status, control, and configuration information for the battery protection system.

Table 10. Register Descriptions

(1) Write and read data will be match after write EEPROM writing procedure.

Table 11. Register Map

NAME		$I2C$ ADDR	B7	B6	B5	B4	B ₃	B2	B1	B0
STATUS		0x00	CHG	DSG	VGOOD	OVTEMP	UV	OV	OCD	SCD
OUTPUT CONTROL		0x01	FS	PFALT	Ω	Ω	GPOD	CHG	DSG	LTCLR
STATE CONTROL		0x02	IGAIN	VGAIN	$\mathbf 0$	Ω	Ω	$\mathbf 0$	HOST	SHDN
FUNCTION CONTROL [Cell(9,10) balance register]		0x03	CBAL10	CBAL9	TOUT	BAT	PACK	IACAL	IAEN	VAEN
CELL BALANCE		0x04	CBAL8	CBAL7	CBAL6	CBAL5	CBAL4	CBAL3	CBAL2	CBAL1
CELL SEL		0x05	0	CAL ₂	CAL ₁	CAL ₀	CELL4	CELL3	CELL ₂	CELL1
OV CFG		0x06	OV _D 2	OV _{D1}	OVD ₀	OVH ₁	OVH ₀	OV ₂	OV ₁	OV ₀
UV CFG		0x07	Ω	UVFET DIS	UVH ₁	UVH ₀	UV ₃	UV ₂	UV ₁	UV ₀
OCV&UV DELAY		0x08	UVD ₃	UVD ₂	UVD ₁	UVD ₀	OCD ₃	OCD ₂	OCD ₁	OCD ₀
OCD CFG		0x09	CBEN	ZVC	SOR	OCDD4	OCDD3	OCDD ₂	OCDD1	OCDD ₀
SCD CFG		0x0a	SCDD3	SCDD ₂	SCDD1	SCDD ₀	SCD ₃	SCD ₂	SCD ₁	SCD ₀
EEPROM	Read-writing	0x0b	0			$\mathbf 0$	0	$\mathbf 0$		$\mathbf 0$
	Writing (0x41)		0		$\mathbf 0$	0	0	$\mathbf 0$	0	
	Reading (except above)		$\mathbf 0$	$\mathbf{0}$	Ω	Ω	$\mathbf 0$	$\mathbf 0$	$\mathbf 0$	$\mathbf 0$

Register Control

0x01 to 0x05 should be controlled during host-control mode.

STATUS: Status Register

The STATUS register provides information about the current state of the bq77PL900.

STATUS b0 (SCD): This bit indicates a short-circuit in discharge condition.

- $0 =$ Current is below the short-circuit in discharge threshold (default).
- 1 = Current is greater than or equal to the short-circuit in discharge threshold.

STATUS b1 (OCD): This bit indicates an overload condition.

- $0 =$ Current is less than or equal to the overload threshold (default).
- $1 =$ Current is greater than the overload threshold.

STATUS b2 (OV): This bit indicates an overvoltage condition.

- $0 =$ Voltage is less than or equal to the overvoltage threshold (default).
- 1 = Voltage is greater than the overvoltage threshold.

STATUS b3 (UV): This bit indicates an undervoltage condition.

- $0 =$ Voltage is greater than or equal to the undervoltage threshold (default).
- 1 = Voltage is less than the undervoltage threshold.

STATUS b4 (OVTEMP): This bit indicates an overtemperature condition.

- 0 = Temperature is lower than or equal to the overtemperature threshold (default).
- 1 = Temperature is higher than the overtemperature threshold.

STATUS b5 (VGOOD): This bit indicates a valid EEPROM power-supply voltage condition.

- 0 = Voltage is smaller than specified EEPROM power-supply voltage (default).
- 1 = Voltage is greater than or equal to the specified EEPROM power-supply voltage.

STATUS b6 (DSG): This bit reports the external discharge FET state.

- $0 =$ Discharge FET is off.
- 1 = Discharge FET is on.

STATUS b7 (CHG): This bit reports the external charge FET state.

- $0 =$ Charge FET is off.
- 1 = Charge FET is on.

 $\text{SLUSS44B–JUNE } 2008-\text{REVISED JANUARY } 2009 \newline \text{MWW-} \text{Licom } 1000 \newline \text{MWW-} \text{Licom } 10$

OUTPUT_CONTROL: Output Control Register

The OUPTUT CONTROL register controls some of the outputs of the bq77PL900 and can show the state of the external pin corresponding to the control.

OUTPUT_ CONTROL b0 (LTCLR): When a fault is latched, this bit releases the fault latch when toggled (default).

0→1→0 clears the fault latches, allowing STATUS to be cleared on its next read.

OUTPUT_ CONTROL b1 (DSG): This bit controls the external discharge FET.

0 = Discharge FET is OFF in host-control mode.

1 = Discharge FET is ON in host-control mode.

OUTPUT CONTROL b2 (CHG): This bit controls the external charge FET.

0 = Charge FET is OFF in host-control mode.

1 = Charge FET is ON in host-control mode.

OUTPUT_CONTROL b3 (GPOD): This bit enables or disables the GPOD output.

 $0 = GPOD$ output is high impedance (default).

1 = GPOD output is active (GND).

OUTPUT CONTROL b6 (PFALT): This bit indicates a parity error in the EEPROM. This bit is read-only.

 $0 =$ No parity error (default)

 $1 = A$ parity error has occurred.

OUTPUT_CONTROL b7 (FS): This bit selects the undervoltage detection sampling time.

 $0 =$ Sampling time is 50 ms/cell (typ) (default).

 $1 =$ Sampling time is 100 μ s/cell (typ)

OUTPUT CONTROL b6-b4: These bits are not used and should be set to 0.

STATE_CONTROL: State Control Register

The STATE_CONTROL register controls the states of the bq77PL900.

STATE_CONTROL b0 (SHDN): This bit enables or disables the shut down mode in host mode.

- 0 = Disable shutdown mode (default).
- 1 = Enable shutdown mode (if PACK voltage = 0 V).

STATE_CONTROL b1 (HOST): This bit selects stand-alone mode or host-control mode.

- 0 = Stand-alone mode (default)
- $1 =$ Host control mode

STATE_CONTROL b6 (VGAIN): This bit controls the cell amplifier scale.

 $0 =$ SCALE is 0.15 (default).

 $1 =$ SCALE is 0.2.

STATE_CONTROL b7 (IGAIN): This bit controls the current monitor amplifier gain.

 $0 =$ GAIN is 10 (default).

 $1 =$ GAIN is 50.

STATE_CONTROL b5-b2: These bits are not used and should be set to 0.

FUNCTION_CONTROL: Function Control Register, [Cell (9, 10) Balance Register]

The FUNCTION_CONTROL register controls some features of the bq77PL900.

FUNCTION_ CONTROL b0 (VAEN): This bit controls the internal cell-voltage amplifier.

 $0 =$ Disable cell-voltage amplifier (default).

1 = Enable cell-voltage amplifier.

FUNCTION CONTROL b1 (IAEN): This bit controls the internal current-monitor amplifier.

 $0 =$ Disable current-monitor amplifier (default).

1 = Enable current-monitor amplifier.

FUNCTION_CONTROL b2 (IACAL): This bit controls the internal current-monitor amplifier offset-voltage output.

0 = Disable offset voltage output (default).

1 = Enable offset voltage output.

FUNCTION CONTROL b3 (PACK): When VAEN $= 1$, PACK input is divided by 50 and presented on VCELL

 $0 =$ Disable pack total voltage output (default).

1 = Enable pack total voltage output.

FUNCTION CONTROL b4 (BAT): When VAEN $= 1$, BAT input is divided by 50 and presented on VCELL.

 $0 =$ Disable pack total voltage output (default).

 $1 =$ Enable pack total voltage output.

This bit priority is higher than PACK(b3).

FUNCTION _CONTROL b5 (TOUT): This bit controls the power to the thermistor.

- 0 = Thermistor power is off in host-control mode (default).
- $1 =$ Thermistor power is on in host-control mode.

FUNCTION CONTROL b7–b6 (CELL10–9): This bit enables or disables the cell 9 and cell 10 balance charge bypass path

- $0 =$ Disable bottom series cell 9 or cell 10 balance charge bypass path (default).
- 1 = Enable bottom series cell 9 or cell 10 balance charge bypass path.

CELL_BALANCE: Cell (1 to 8) Balance Register

The CELL_BALANCE register controls cell balancing of the bq77PL900.

CELL_BALANCE b7(CBAL8): This bit enables VC3–VC4 cell balance charge bypass path.

CELL_BALANCE b6(CBAL7): This bit enables VC4–VC5 cell balance charge bypass path.

CELL_BALANCE b5(CBAL6): This bit enables VC5–VC6 cell balance charge bypass path.

CELL_BALANCE b4(CBAL5): This bit enables VC6–VC7 cell balance charge bypass path.

CELL_BALANCE b3(CBAL4): This bit enables VC7–VC8 cell balance charge bypass path.

CELL_BALANCE b2(CBAL3): This bit enables VC8–VC9 cell balance charge bypass path.

CELL_BALANCE b1(CBAL2): This bit enables VC9–VC10 cell balance charge bypass path.

CELL_BALANCE b0(CBAL1): This bit enables VC10–VC11 cell balance charge bypass path.

0 = Disable series cell balance charge bypass path (default).

 $1 =$ Enable series cell balance charge bypass path.

CELL_SEL: Cell Translation Selection and Cell Translation Status Register

The CELL_SEL register determines the cell selection for voltage measurement and translation. The register also determines operation mode of the cell voltage monitoring.

The CELL SEL b6–b4 (CAL2–CAL0) bits should be 0 when VAEN(b0) in register 3 is changed from 0 to 1 or the VOUT pin will not go active.

This register is don't care when either BAT(b4) or PACK(b3) is set or VAEN(b0) is cleared in register 3.

CELL_SEL b3–b0 (CELL4–1): These four bits select the series cell for voltage measurement translation. These are don't care when CAL2–0 are not equal to 0x0.

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 $\text{SLUSS44B–JUNE } 2008-\text{REVISED JANUARY } 2009 \newline \text{MWW-} \text{Licom } 1000 \newline \text{MWW-} \text{Licom } 10$

CELL_SEL b6–b4 (CAL2–0): These three bits determine the mode of the voltage monitor block.

(1) When $VGAIN = 0$, $VREF = 0.975 V$; when $VGAIN = 1$, $VREF = 1.2 V$.

CELL_SEL b7: These bits are not used and should be set to 0.

OV_CFG: Overvoltage Delay Time, Hysteresis, and Threshold Configuration Register

The OV register determines cell overvoltage threshold, hysteresis voltage, and detection delay time.

OV_CFG b2–b0 (OV2–0) configuration bits with corresponding voltage threshold with a default of 000. Resolution is 50 mV.

OV_CFG b4–b3 (OVH1–0) configuration bits with corresponding hysteresis voltage with a default of 00. Resolution is 100 mV.

OV CFG b7–b5 (OVD2–0) configuration bits with corresponding delay time for overvoltage with a default of 000. Resolution is 250 ms.

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UV_CFG: Undervoltage Hysteresis and Threshold Configuration Register

The UV register determines the cell undervoltage threshold, hysteresis voltage, and detection delay time.

UV CFG b2–b0 (UV3–0) configuration bits with corresponding voltage threshold with a default of 000. Resolution is 100 mV.

UV_CFG b5–b4 (UVH1–0) configuration bits with corresponding hysteresis voltage with a default of 00. Resolution is 200 mV.

When the undervoltage threshold and the hysteresis values are high, then undervoltage recovery may not occur. To avoid this, Table 12 should be used for assistance in configuration.

Table 12. Combination of UV Release Voltage vs Hysteresis

UV_CFG b6 (UVFET_DIS): This bit disable automatically turns off the DSG output when UV is detected in host-control mode.

- 0 = DSG output changes to OFF when UV is detected (default).
- 1 = DSG output does not change to OFF when UV is detected. But the UV bit of the status register (0x00) is changed, even if this bit = 1.

UV CFG b7: This bit should be set to 0, so that the bq77PL900 protects battery cell safety.

INSTRUMENTS

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OC&UV_DELAY: Overcurrent and Undervoltage Delay Register

The FUNCTION and OCDV CFG register determines overcurrent in discharge voltage threshold and controls functions.

OC&UV_DELAY b3–b0 (OCD3–0) configuration bits with corresponding voltage threshold. Resolution is 5 mV.

OC&UVDELAY b7–hb4 (UVD3–0) configuration bits with corresponding delay time for undervoltage with a default of 000. Resolution is 1 s when the FS bit = 0.

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OCD_CFG: Overcurrent in Discharge Configuration Register

The FUNCTION & OCD CFG register determines function and overload-detection delay time.

OCD_CFG b4–b0 (OCDD4–0) configuration bits with corresponding delay time. Units are in ms and resolution is 20 ms or 100 ms.

OCD_CFG b5 (SOR): Recover condition from SC and OC with stand-alone mode

- 0 = Recover by attaching a charger. Recover comparator is active after 12.8 s for OC/SC detection (default).
- 1 = Recover by SC/OC condition released. Recovery from OC/SC after 12.8 s.

OCD_CFG b6 (ZVC): This bit controls the 0-V/precharge of the GPOD output.

- 0 = Disable the GPOD output 0-V/precharge mode with stand-alone (default).
- 1 = Enable the GPOD output 0-V/precharge mode with stand-alone.
- OCD_CFG b7 (CBEN): This bit controls cell balancing.
	- $0 =$ Disable the cell balancing function (default)
	- $1 =$ Enable the cell balancing function.

EXAS **NSTRUMENTS**

 $\text{SLUSS44B–JUNE } 2008-\text{REVISED JANUARY } 2009 \newline \text{MWW-} \text{Licom } 1000 \newline \text{MWW-} \text{Licom } 10$

SCD_CFG: Short-Circuit in Discharge Configuration Register

The SCD_CFG register determines the short-circuit voltage threshold and detection delay time.

SCD CFG b3-b0 (SCD3-0): These lower-nibble bits select the value of the short-circuit in discharge voltage threshold with 0000 as the default, units in mV, and a resolution of 5 mV.

SCD CFG b7-b4 (SCDD3-0): These upper nibble bits select the value of the short circuit in discharge delay time. 0000 is the default, units of us and a resolution of 60us.

EEPROM: EEPROM Write Enable and Configurati0n Register

EEPROM b7–b0 (EEPROM7–0):

These bits enable data write to EEPROM(0x06-0x9a) with 0100 0001 (0x41).

Prewriting data is available by setting these bits with 0110 0010 (0x62).

Default is 0000 0000 (0x00).

Zero-Volt Charging

In order to charge cells, the CHG FET must be turned on to create a current path. When the battery voltage (V_{BAT}) is low and the CHG is ON, the pack voltage (V_{PACK}) is as low as the battery voltage. In cases where the level is below the supply voltage for the bq77PL900 is too low to operate, there are two configurations to provide the appropriate 0-V/precharge function.

Common FET mode does not require a dedicated 0-V/precharge FET. The CHG FET is ON. This method is suitable for a charger that has a 0-V/precharge function. The second mode is to use a 0-V/precharge FET which establishes a dedicated 0-V/precharge current path by using an additional open drain (GPOD output) for driving an external FET (PCHG FET). This configuration sustains the PACK+ voltage level. Any type of charger can be used with this configuration.

Table 13. 0-V Charge Summary

Common FET

In this mode, the PMS pin is connected to PACK+. In this configuration, the charger must have a 0-V/precharging function which is typically controlled as follows:

- The cell voltage is lower than a certain constant voltage (normally about 3 V/cell). – Apply 0-V/precharging current.
- The cell voltage is higher than a certain constant voltage (normally about 3 V/cell).
	- Apply fast-charging current.

When the charger is connected and VPMS is greater than or equal to 0.7 V, the CHG FET is turned ON. The charging current flows through the CHG FET and the back diode of the DSG.

 $V_{PACK+} = V_{BAT} + 0.7 V (VF: forward voltage of a DSG-FET back diode) + V_{DS}(CHG-FET)$

Figure 27. Common FET Circuit Diagram

When the PACK pin voltage is maintained at higher than 0.7 V and the precharging current is maintained, the PACK voltage and BAT voltage are under the minimum bq77PL900 supply voltage, so the regulator is inactive.

When the BAT voltage rises and the PACK pin voltage reaches the bq77PL900 minimum supply voltage, an internal 3.3-V regulator is turned ON. Then, the CHG FET state is controlled by UVP and OVP functions. When the all the cell voltages reach fast-charge voltage (about 3 V per cell), the charger starts the fast-charging mode.

 $\text{SLUSS44B–JUNE } 2008-\text{REVISED JANUARY } 2009 \newline \text{MWW-} \text{Licom } 1000 \newline \text{MWW-} \text{Licom } 10$

Figure 28. Signal Timing of Pins During 0-V/Precharging

8.22.2 0-V/Precharge FET in Host Control Mode

In this configuration, the charger does not have a requirement to support a precharge function. Thus, the host controller and bq77PL900 must limit the fast charging current to a suitable 0-V/precharge level.

The PMS pin is connected to GND and a 0-V/precharge current flows through a dedicated 0-V/precharge FET (PCHG FET).

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Figure 29. 0-V/Precharge FET Circuit in Host-Control Mode

The 0-V/precharge FET is driven by the GPOD output. By setting the GPOD bit to 1, the GPOD output turns ON, and then the PCHG FET. The 0-V/precharge current is limited by the 0-V/precharge FET (PCHG FET) and a series resistor (R(PCHG)) as follows.

 $I_{\text{OV/PCHG}} = I_{\text{D}} = (V_{\text{PACK}_+} - V_{\text{BAT}} - V_{\text{DS}})/R_{\text{P}}$

A load curve of the PCHG FET is shown in Figure 30. When the gate-source voltage (V_{DS}) is high enough, the FET operates in the linear region and has low resistance. By approximating V_{DS} as 0 V, the 0-V/precharge current $(I_{\text{OV/PCHG}})$ is expressed as follows.

 $I_{\text{OV/PCHG}} = (V_{\text{PACK}_+} - V_{\text{BAT}}) / R_{\text{P}}$

Figure 30. 0V/PCHG FET ID and VDS Characteristics

 $\text{SLUSS44B–JUNE } 2008-\text{REVISED JANUARY } 2009 \newline \text{MWW-} \text{Licom } 1000 \newline \text{MWW-} \text{Licom } 10$

EXAS INSTRUMENTS

During the 0-V/precharge, the CHG FET is turned OFF and the PCHG FET is turned ON. When the host controller detects that all the cell voltages have reached the fast-charge threshold, it then turns ON the CHG FET and turns OFF the PCHG FET. The signal timing is shown in Figure 31.

The CHG, DSG and PCHG FETs are turned OFF when the charger is connected. Then, the charger applies its maximum output voltage (constant-voltage-mode output voltage) to the PACK+ pin. Then, the bq77PL900 3.3-V regulator becomes active and supplies power to the host controller. As the host controller starts up, it turns on the GPOD output and the 0-V/precharge current begins to flow.

In this configuration, attention is needed to control high power consumption at the PCHG FET and the series resistor (R_P) . The highest power is consumed at 0-V cell voltage (highest voltage between PACK+ and BAT pins) and it results in highest heat generation. For example, the power consumption in 10 series batteries with 42-V fast charge voltage and 1-kΩ \overline{R}_P is expressed as follows.

 $I_{\text{OVPCHG}} = (42 \text{ V} - 0 \text{ V}) / 1 \text{ k}\Omega = 42 \text{ mA}$

(Power consumption at R_P) = 42 V \times 42 mA = 1.6 W

It is recommended to combine the resistor (R_P) and the thermistor to reduce the consumption. Once the cell voltage reaches the fast-charge threshold, the host controller turns ON the CHG and DSG FETs and also turns OFF the PCHG FET.

Figure 31. Signal Timing of Pins During 0-V Charging and Precharging (Precharge FET) With Host-Control Mode

0-V/Precharge FER in Stand-Alone Mode

The circuit configuration is the same as 0-V/precharge FET in host-control mode, although in stand-alone mode the bq77PL900 automatically turns on the GPOD output. When the battery voltage reaches 0 V, the charger disable voltage (= PMS disable voltage), the GPOD output is turned OFF, and then the DSG and CHG FETs are controlled by an internal UV comparator function. To activate this mode, set *OCDELAY register [ZVC]*.

Figure 32. 0-V/Precharge FET Circuit Diagram In Stand-Alone Mode

SLUS844B–JUNE 2008–REVISED JANUARY 2009 .. **www.ti.com**

Figure 33. Signal Timing of Pins During 0-V/Precharging (PCHG FET) In Stand-Alone Mode

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PACKAGING INFORMATION

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

⁽²⁾ RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures. "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

Green: TI defines "Green" to mean the content of Chlorine (CI) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

(3) MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead finish/Ball material - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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PACKAGE OPTION ADDENDUM

PACKAGE MATERIALS INFORMATION

TEXAS NSTRUMENTS

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TAPE AND REEL INFORMATION

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

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PACKAGE MATERIALS INFORMATION

*All dimensions are nominal

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TUBE

*All dimensions are nominal

DL (R-PDSO-G48)

PLASTIC SMALL-OUTLINE PACKAGE

- A. All linear dimensions are in inches (millimeters).
	- **B.** This drawing is subject to change without notice.
	- Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15). C.
	- D. Falls within JEDEC MO-118

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